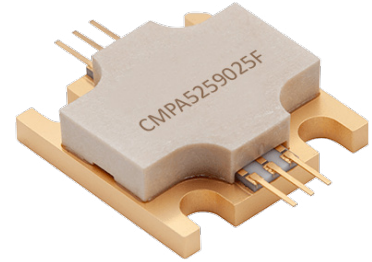


# CMPA5259025F

25 W, 5.2 – 5.9 GHz, 28 V, GaN MMIC for Radar Power Amplifiers

## Description

The CMPA5259025F is a gallium-nitride (GaN) high electron mobility transistor (HEMT) based monolithic microwave integrated circuit (MMIC) designed specifically for high efficiency, high gain, and wide bandwidth capabilities, which makes CMPA5259025F ideal for 5.2 - 5.9 GHz radar amplifier applications. The transistor is supplied in a ceramic/metal flange package.



Package Types: 440219  
PN's: CMPA5259025F

### Features

- 30 dB small signal gain
- 50% efficiency at  $P_{SAT}$
- Operation up to 28 V
- High breakdown voltage

### Applications

- Radar

## Typical Performance Over 5.2 - 5.9 GHz ( $T_c = 25\text{ }^\circ\text{C}$ ) of Demonstration Amplifier

Parameter	5.2 GHz	5.5 GHz	5.9 GHz	Units
Small Signal Gain	33.6	31.9	32.2	dB
Output Power <sup>1</sup>	38.5	39.6	34.8	W
Efficiency <sup>1</sup>	53.5	51.3	47.2	%
Input Return Loss	-13.5	-15.5	-4.8	dB

Note:

<sup>1</sup> 100  $\mu\text{sec}$  pulse width, 10% duty cycle,  $P_{IN} = 22\text{ dBm}$ .



### Absolute Maximum Ratings (Not Simultaneous) at 25 °C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	$V_{DSS}$	84	$V_{DC}$	25 °C
Gate-Source Voltage	$V_{GS}$	-10, +2	$V_{DC}$	25 °C
Storage Temperature	$T_{STG}$	-55, +150	°C	
Operating Junction Temperature	$T_J$	225	°C	
Soldering Temperature	$T_S$	245	°C	
Screw Torque	$\tau$	40	in-oz	
Forward Gate Current	$I_G$	9.6	mA	25 °C
Thermal Resistance, Junction to Case <sup>1</sup>	$R_{\theta JC}$	1.66	°C/W	100 $\mu$ s, 10%, 85 °C
Case Operating Temperature	$T_C$	-40, +105	°C	

Note:

<sup>1</sup> Measured for the CMPA5259025F at  $P_{Diss} = 35$  W.

### Electrical Characteristics ( $T_c = 25$ °C)

Characteristics	Symbol	Min.	Typ.	Max.	Units	Conditions
<b>DC Characteristics<sup>1</sup></b>						
Gate Threshold Voltage	$V_{GS(TH)}$	-3.6	-2.8	-2.4	$V_{DC}$	$V_{DS} = 10$ V, $I_D = 16.5$ mA
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.7	-	$V_{DC}$	$V_{DD} = 28$ V, $I_D = 1.2$ A
Saturated Drain Current	$I_{DS}$	6.9	9.6	-	A	$V_{DS} = 6.0$ V, $V_{GS} = 2.0$ V
Drain-Source Breakdown Voltage	$V_{BD}$	84	-	-	$V_{DC}$	$V_{GS} = -8$ V, $I_D = 16.5$ mA
<b>RF Characteristics<sup>2</sup></b>						
Small Signal Gain	S21	24	32	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 - 5.9 GHz, $P_{IN} = -20$ dBm
Input Return Loss	S11	-	-10	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 - 5.9 GHz, $P_{IN} = -20$ dBm
Output Return Loss	S22	-	-15	-4	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 - 5.9 GHz, $P_{IN} = -20$ dBm
Output Power	$P_{OUT}$	25	38.5	-	W	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 GHz, $P_{IN} = 22$ dBm
Output Power	$P_{OUT}$	25	39.6	-	W	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.5 GHz, $P_{IN} = 22$ dBm
Output Power	$P_{OUT}$	25	34.8	-	W	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.9 GHz, $P_{IN} = 22$ dBm
Power Added Efficiency	PAE	40	54	-	%	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 GHz, $P_{IN} = 22$ dBm
Power Added Efficiency	PAE	40	51	-	%	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.5 GHz, $P_{IN} = 22$ dBm
Power Added Efficiency	PAE	35	47	-	%	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.9 GHz, $P_{IN} = 22$ dBm
Power Gain	$G_p$	-	24	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.2 GHz, $P_{IN} = 22$ dBm
Power Gain	$G_p$	-	24	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.5 GHz, $P_{IN} = 22$ dBm
Power Gain	$G_p$	-	23.4	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 500$ mA, Freq = 5.9 GHz, $P_{IN} = 22$ dBm
Output Mismatch Stress	VSWR	-	3 : 1	-	$\Psi$	No Damage at All Phase Angles, $V_{DD} = 28$ V, $I_{DQ} = 500$ mA, $P_{IN} = 22$ dBm

Notes:

<sup>1</sup> Measured on wafer prior to packaging.

<sup>2</sup> Measured in CMPA5259025F-TB test fixture at pulse width = 100  $\mu$ s, duty cycle = 10%.

Typical Pulsed Performance

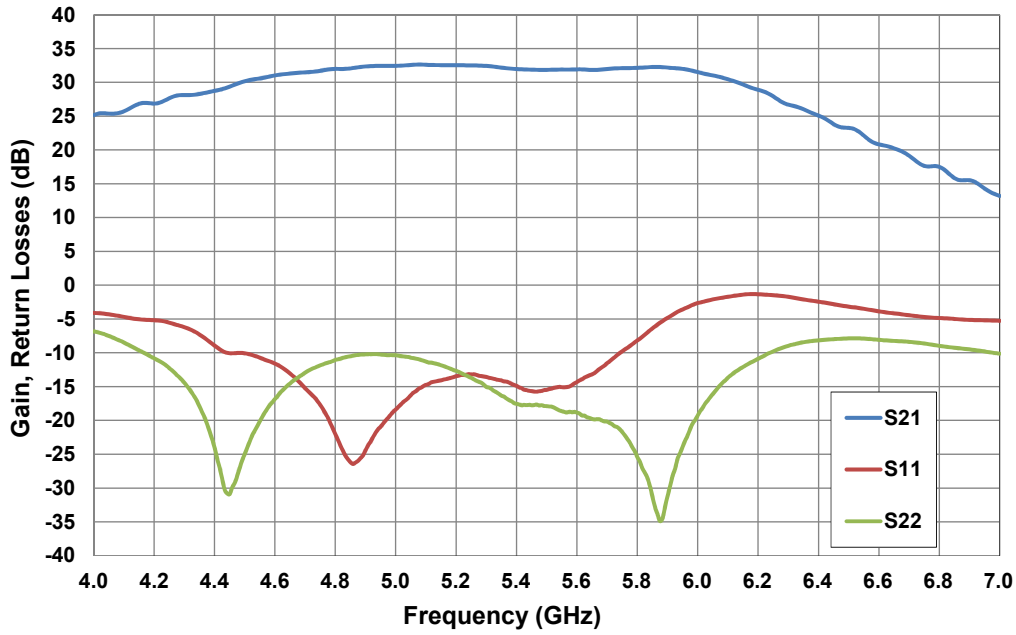


Figure 1. Gain and Return Loss vs Frequency of the CMPA5259025F  
 Measured in CMPA5259025F-AMP Amplifier Circuit  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 0.5\text{ A}$ ,  $T_c = 25\text{ }^\circ\text{C}$

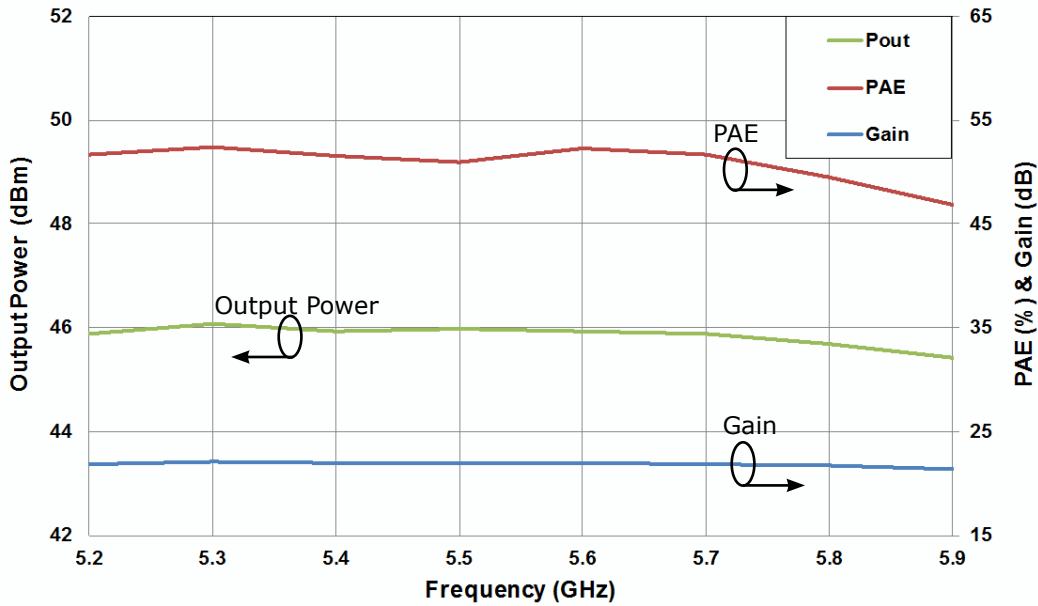


Figure 2. Output Power, Gain, and Power Added Efficiency vs Frequency of the CMPA5259025F  
 Measured in CMPA5259025F-AMP Amplifier Circuit  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 0.5\text{ A}$ ,  $P_{IN} = 24\text{ dBm}$ , Pulse Width = 100  $\mu\text{s}$ , Duty Cycle = 10%,  $T_c = 25\text{ }^\circ\text{C}$

Typical Pulsed Performance

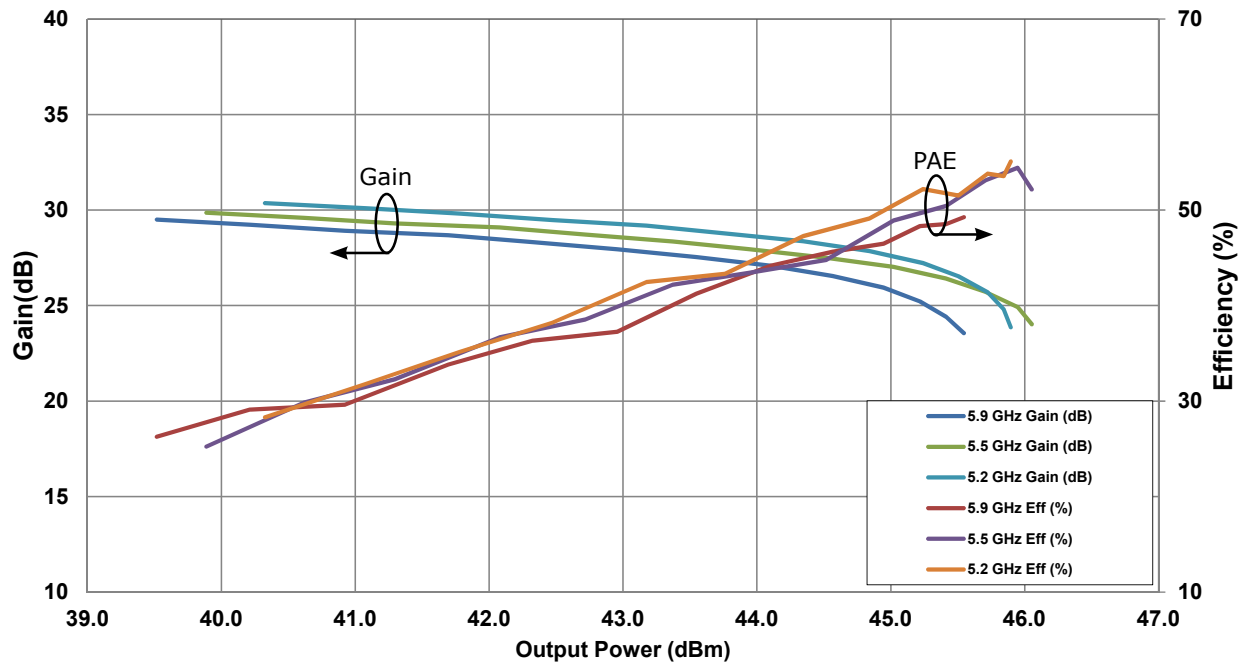
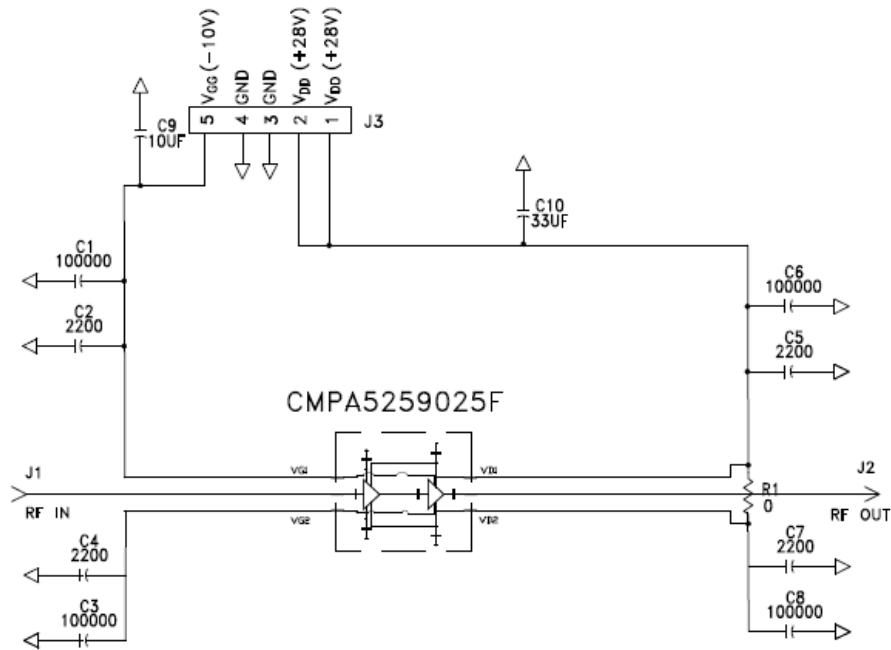
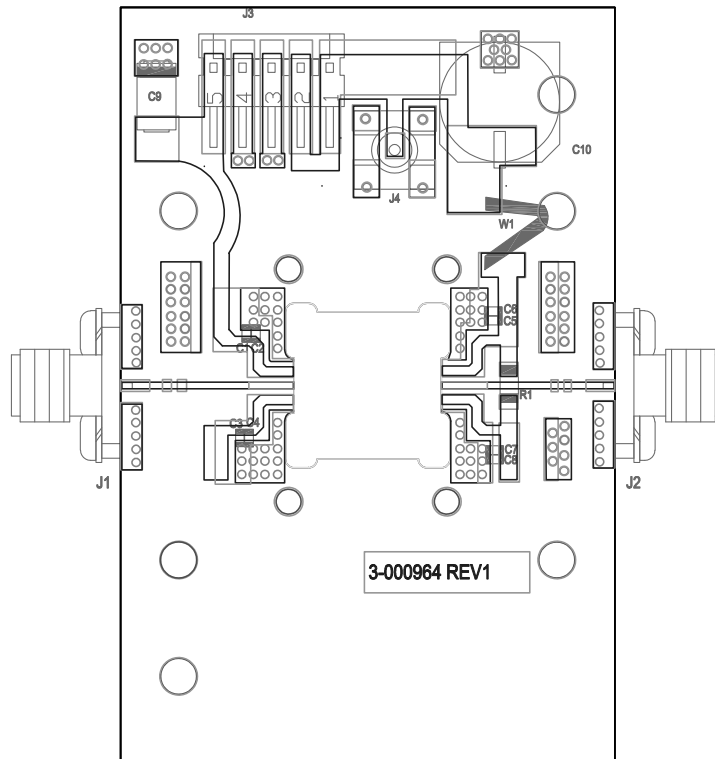


Figure 3. Gain and Power Added Efficiency vs Frequency of the CMPA529025F  
 Measured in CMPA525025F-AMP Amplifier Circuit  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 0.5\text{ A}$ , Pulse Width = 100  $\mu\text{s}$ , Duty Cycle = 10%,  $T_c = 25\text{ }^\circ\text{C}$

### CPMA5259025F-AMP Demonstration Amplifier Schematic



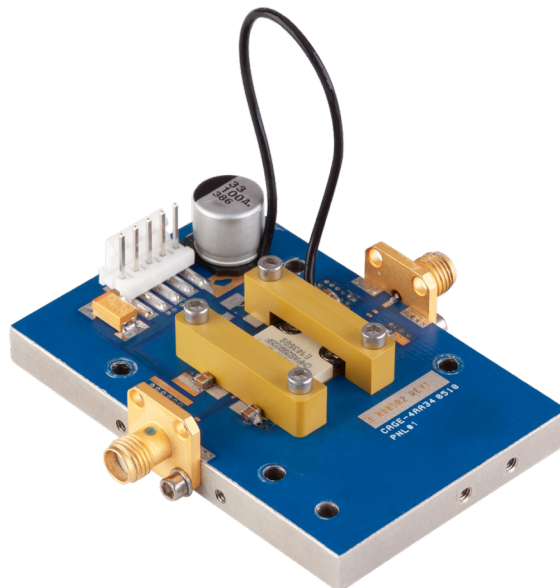
### CPMA5259025F-AMP Demonstration Amplifier Circuit Outline



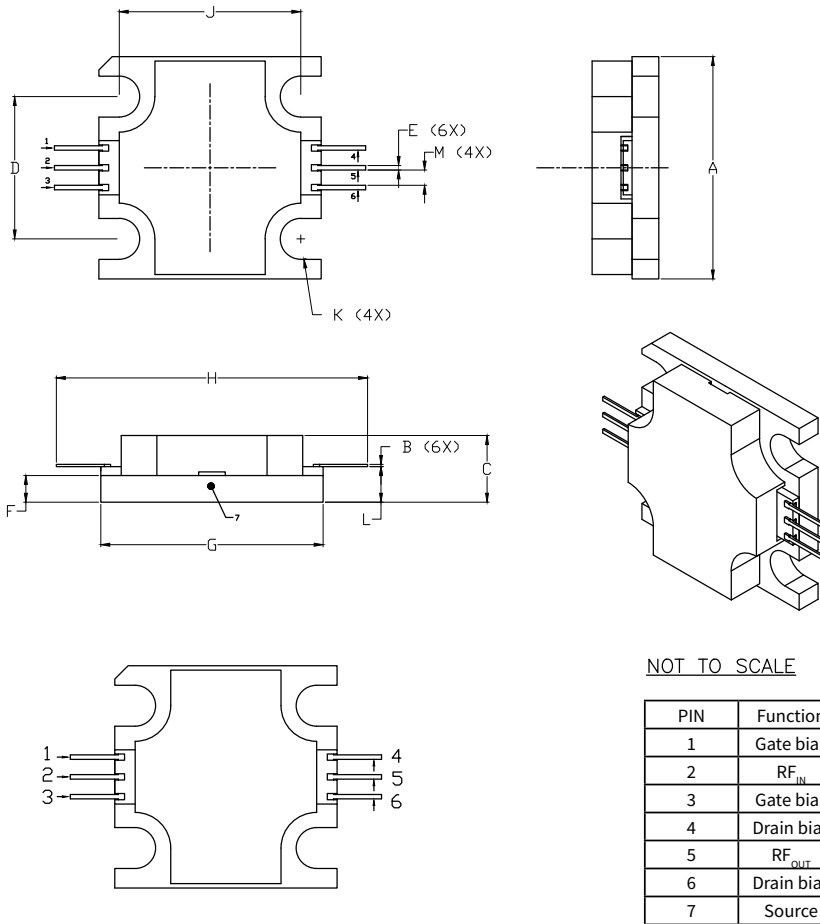
### CMPA5259025F-TB Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
R1	RES 0 OHM, SMT, 1206, 125 mW	1
C1, C3, C6, C8	CAP, 100000 pF, (0.1 UF) +/- 10%, 100 V, 0805	4
C2, C4, C5, C7	CAP, 0805, 2200 pF, 100 V, 0805	4
C9	CAP, 10 UF, 16 V, Tantalum	1
C10	CAP, 33 UF, 20%, G Case	1
J3	Header RT> PLZ .1 CEN LK 5POS	1
J1, J2	CONN, SMA, Female, 2-Hole, Flange	2
J4	CONN, SMB, Straight Jack Receptacle, SMT, 50 OHM, Au Plated	1
	Baseplate, AL, 2.60 X 1.7 X 0.25	1
	#4 Split Lockwasher SS	4
	2-56 SoC HD Screw 3/16 SS	4
	#2 Split Lockwasher SS	4
	4-40 SOC HD Screw 3/8" SS	4
	PCB, Taconics, RF 35, CMPA5259025F 0.010" THK	1
W1	Wire, Black, 22 AWG ~ 3"	

### CMPA5259025F-AMP Demonstration Amplifier Circuit



**Product Dimensions CMPA5259025F (Package Type – 440219)**



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.
5. ALL PLATED SURFACES ARE NI/AU

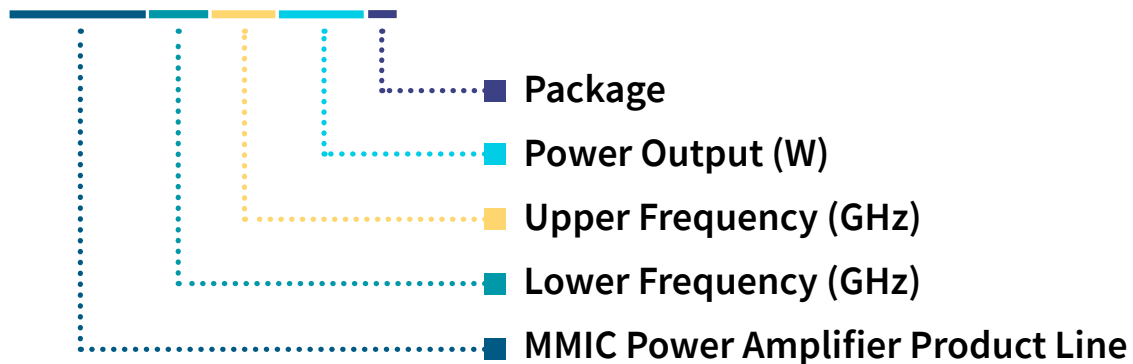
DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.495	0.505	12.57	12.82
B	0.003	0.005	0.076	0.127
C	0.140	0.160	3.56	4.06
D	0.315	0.325	8.00	8.25
E	0.008	0.012	0.204	0.304
F	0.055	0.065	1.40	1.65
G	0.495	0.505	12.57	12.82
H	0.695	0.705	17.65	17.91
J	0.403	0.413	10.24	10.49
K	∅ .092		2.34	
L	0.075	0.085	1.905	2.159
M	0.032	0.040	0.82	1.02

**Electrostatic Discharge (ESD) Classifications**

Parameter	Symbol	Class	Test Methodology
Human Body Model	HBM	1A (> 250 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	2 (125 V < 250 V)	JEDEC JESD22 C101-C

**Part Number System**

# CMPA5259025F



**Table 1.**

Parameter	Value	Units
Lower Frequency	5.2	GHz
Upper Frequency <sup>1</sup>	5.9	GHz
Power Output	25	W
Package	Flange	-

Note:

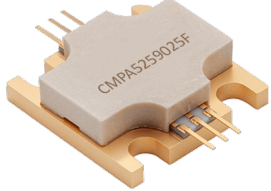
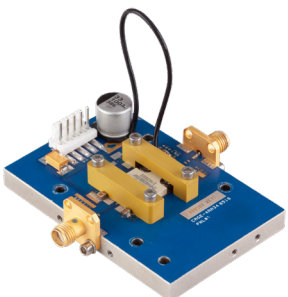
<sup>1</sup>Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

**Table 2.**

Character Code	Code Value
A	0
B	1
C	2
D	3
E	4
F	5
G	6
H	7
J	8
K	9
Examples:	1 A = 10.0 GHz 2 H = 27.0 GHz



**Product Ordering Information**

Order Number	Description	Unit of Measure	Image
CMPA5259025F	GaN MMIC	Each	
CMPA5259025F-AMP	Test Board with GaN MMIC Installed	Each	

## Notes & Disclaimer

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